## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re	Patent	Application of						
MIZUKI et al. Atty. Ref.: 829-621								
Seria	No.	To be Assigned	Group:					
Filed	:	February 10, 2004	Examiner:					
For:	THI DIS	SEMICONDUCTOR FILM AND METHOD OF FORMING THE SAME, AND SEMICONDUCTOR DEVICE AND DISPLAY APPARATUS USING THE SEMICONDUCTOR FILM						
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			February 10,	2004				
P.O.	Box 1	ner for Patents 450 , VA 22313-1450						
Sir:								
		INFORMATION DISCLOSURE	STATEMENT					
$\boxtimes$	1.	PTO-1449 Pursuant to 37 CFR 1.97(b) [within 3 months of filing or prior to 1st Office	e Action]	N/C				
	2.	Statement Pursuant to 37 CFR 1.97(c) [before Final Office Action and Allowance]		N/C				
	3.	Fee Payment Pursuant to 37 CFR 1.97(c) [before Final Office Action and Allowance]		\$180.00				
	4.	Pursuant to 37 CFR 1.97(d) [before Issue Fee payment]		\$180.00				
	The	following are submitted in the above-identified	application in	compliance with 37				
C.F.R	§§ 1.	97 and 1.98:						
	5.	A list of documents on Form PTO-1449. Actual copies of the references listed on the attached form PTO-1449 are not included herewith in accordance with MPEP §609, these references being previously submitted in any and all of the parent applications. The parent application includes U.S. application Serial No. 10/294,760.						

This	paper	is	subi	mitte	d in	accord	lance	with:

$\boxtimes$	6.	37 CFR 1.97(b): [within 3 months of filing or prior to 1st Office Action]
	7.	37 CFR 1.97(c): [before Final Office Action and Allowance, whichever is earlier]; and
		a) The required Statement made in item 9 below; or
		b) The \$180.00 fee specified in 37 CFR §1.17(p) for submission of this Information Disclosure Statement is authorized in item 10 below.
	8.	37 CFR §1.97(d): [before issue fee payment]; and
		a) The fee (\$180.00) required by 37 CFR §1.17(p) is authorized in item 10 below; and
		b) The required Statement is stated in item 9 below.
	9.	Statement under 37 CFR 1.97(e)
		a) The undersigned attorney of record hereby certifies under 37 C.F.R. §1.97(e) that each item of information contained in this Information Disclosure Statement was first cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this Information Disclosure Statement (each item contained in this IDS was the first citation of that item by a foreign patent office in a counterpart foreign application which occurred no more than three months prior to the filing of this IDS); or
		b) No item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the person signing this Statement, after making reasonable inquiry, no item of information contained in this Statement was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this Information Disclosure Statement.
$\boxtimes$	10.	Please charge all applicable fees associated with the submission of this Information

Respectfully submitted,

Disclosure Statement and any other fees applicable to this application to Deposit Account No. 14-1140. An original and one (1) copy of this document are enclosed.

NIXON & VANDERHYE P.C.

By:

Joseph A. Rhoa Reg. No. 37,515 MIZUKI et al. Serial No. To be Assigned

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JAR:caj 1100 North Glebe Road, 8th Floor Arlington, VA 22201-4714 Telephone: (703) 816-4000 Facsimile: (703) 816-4100

PERIOD TO THER DOCUMENTS (Including Author, Title, Date, Pertinent pages, etc.)    Course several sheets if recessary)   FOREIGN PATENT DOCUMENTS   FAMILY   February 10, 2004	INFO	RMATION DISCLOSURE CITATION	829-621		To be Assigned				
FILING DATE   GROCOPE   February 10, 2004		CITATION							
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U.S. PATENT DOCUMENTS    System   Date   Name   Class   Subclass   Farroprinate	(L	Jse several sheets if necessary)			GROUP				
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FOREIGN PATENT DOCUMENTS  FOREIGN PATENT DOCUMENTS  TRANSLATION OCUMENT DATE COUNTRY CLASS SUBCLASS YES NO 2000-150382 5/2000 JP  OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)  U.S. Patent Application Serial No. 10/294,760 filed November 15, 2002 A. Hara et al., "Limit of Mobility Enhancement of Excimer Laser Crystallized Poly-Si TFTs"; TECHNICAL REPORT OF IEICE; Vol. 100, No. 2; pp 27-32.		DOCUMENT NUMBER			CLASS	SUBCLASS			
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examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.	Examiner: Initia	I if reference considered, whether or	not citation is in c	conformance with MPEP 609; Draw line through	citation if not in conform	nance and not co	nsidered. I	nclude	

Form PTO-FB-A820 (Also PTO-1449)